

# Update on direct photon calorimeter

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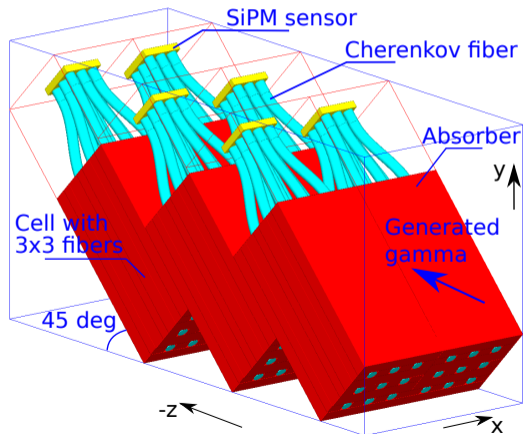
# Outline

- Improvement in light yield by radiator fibers directly in air, no cladding
- Fiber diameter reduced to 1 mm (from 1.5) due to commercial availability
- Absorber material as Pb (changed from Cu) for smaller shower size
- Realistic photon detection efficiency for SiPM is applied

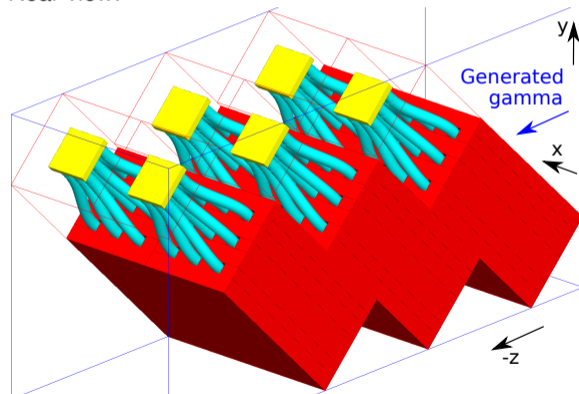
# Simulation geometry

- Cherenkov quartz fibers of 1 mm diameter in grooves in Pb absorber at 4 mm spacing
- Cells of  $12.2 \times 12.2 \times 264$  mm, 3x3 fibers, absorber and SiPM at  $45^\circ$ , bent fibers of 35 mm
- 15 cells along x, 20 cells along z, total size is 180 mm (x), 195 mm (y), 520 mm (z)

Front view:



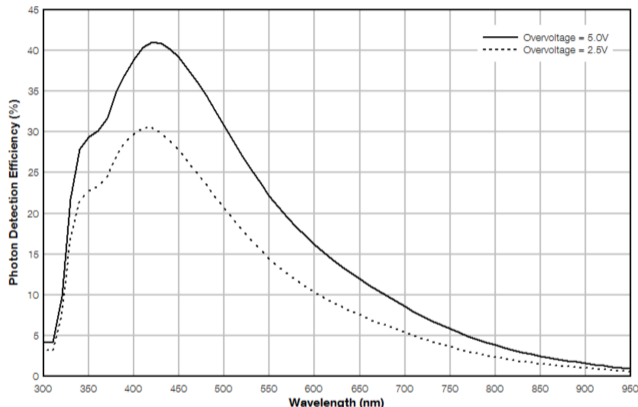
Rear view:



# SiPM photon detection efficiency

- Onsemi 30035 C-series, P-on-N
- Active area  $3 \times 3 \text{ mm}^2$ , 4774 microcells
- Microcell size  $35 \text{ }\mu\text{m}$ , fill factor 64%
- Photon Detection Efficiency (PDE) is probability for incident photon to produce an avalanche in a microcell
- PDE is given by quantum efficiency of silicon  $\eta(\lambda)$ , probability to initiate an avalanche  $\epsilon(V)$  and fill factor of the sensor  $F$ :

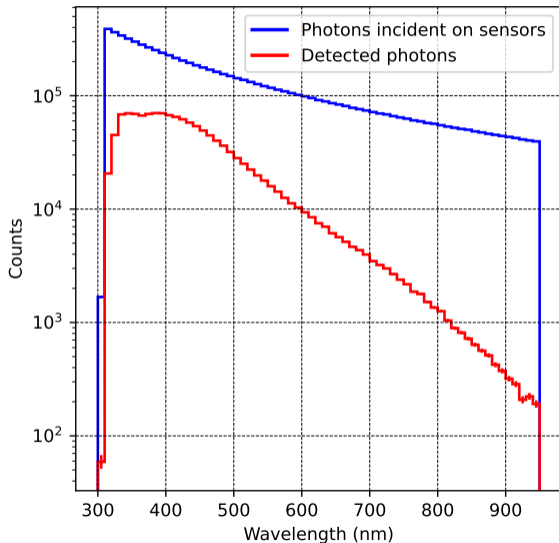
$$\text{PDE}(\lambda, V) = \eta(\lambda) \cdot \epsilon(V) \cdot F$$



- Plot shows the PDE for Onsemi 30035 as a function of wavelength  $\lambda$  and overvoltage  $V$
- Using overvoltage  $V = 2.5 \text{ V}$  in the following as a conservative approach

# Applying the SiPM PDE in Geant simulation

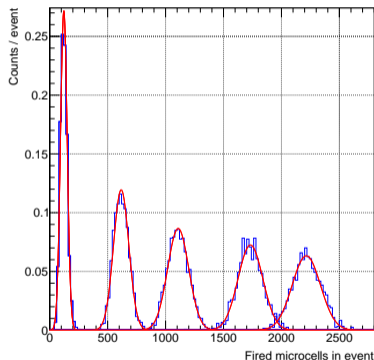
- SiPM sensors are represented by Si slabs, counting the incident photons transported in fibers as hits
- For each incident photon a uniform random number between 0 and 1 is generated
- The photon is marked as detected when the number is less than PDE at a given wavelength
- e.g. for a photon at 500 nm the number must be less than 0.3 for it to be detected
- Number of such detected photons is number of fired microcells in a sensor, realistic measurable signal
- Plot shows example for 9 GeV  $\gamma$  photons



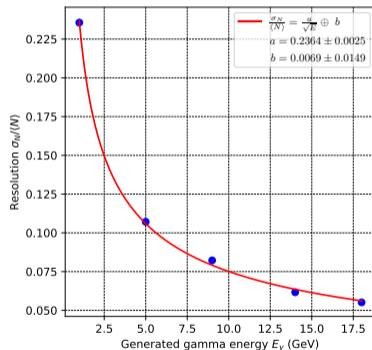
# Energy resolution by number of fired microcells

- Yields by number of fired microcells in event by applying  $\lambda$ -dependent PDE
- Energy resolution by sigma/mean in the yields
- Set of  $\gamma$  energies from 1 to 18 GeV
- 1200  $\gamma$ s simulated at each energy

Fired microcell yields:

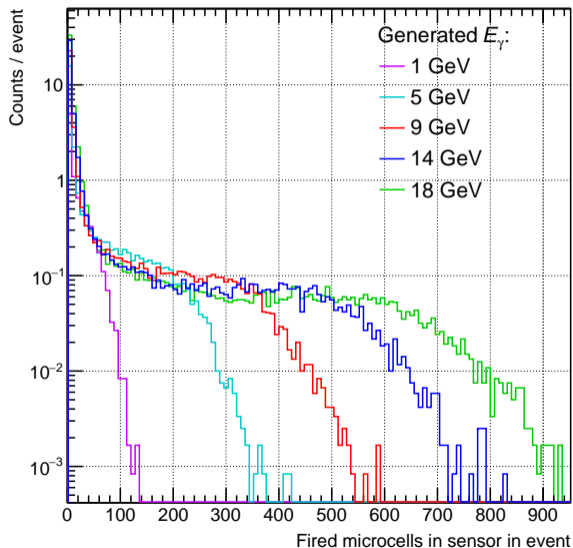


Energy resolution:



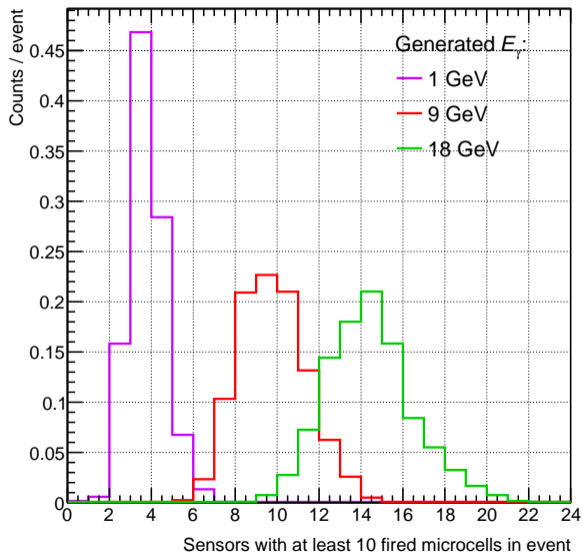
# Fired microcells in sensor

- Number of fired microcells in individual sensors after  $\lambda$ -dependent PDE in event
- Realistic signal expected from the SiPMs
- There is  $\sim 4700$  microcells in a sensor, signals are well within its dynamic range
- In one in 10 events we can find sensors with 100 – 300 fired microcells for all  $\gamma$  energies



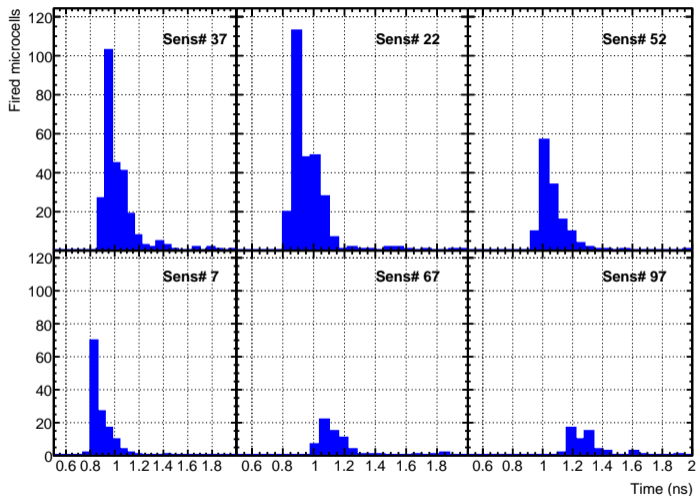
# Fired microcells above a threshold

- Threshold of at least 10 fired microcells in individual sensors
- Plot shows distribution of counts of sensors above the threshold in event
- In each event there is a few sensors above the 10 fired microcells threshold



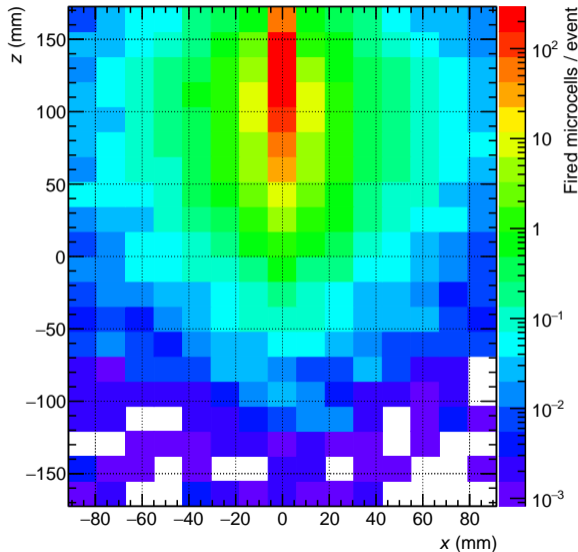
# Time distribution in fired microcells

- Time stamps when a fired microcell was recorded in a sensor
- Shown for a typical event at 9 GeV
- 6 sensors with the highest signal
- All signal is created within 0.4 ns
- Looks ok for 10 ns bunch spacing



# Spatial distribution in fired microcells

- Fired microcells per event along  $x$  and  $z$
- Each bin is a calorimeter cell (looking from the top)
- Plot done for 9 GeV  $\gamma$ , other energies look similar
- Showers are mostly contained in the middle column of the cells



## Next steps

- Looks feasible to get sufficiently short measurable signal
- Plan to proceed with Technical Paper (JINST) based on results shown here
- Then placing the Geant model in EIC position after luminosity magnets and running with GETaLM events
- Vertical size might need to be larger to prevent shower leaking into SiPMs (or larger fiber spacing or W powder absorber)
- Hardware development ongoing for signal amplification and shaping